

WN3S30S200CBT

Dual power Schottky diode

Rev.01 - 21 April 2023

Preliminary data sheet

1. General description

Dual common cathode power Schottky diode in TO263 (D2PAK) plastic package.



2. Features and benefits

- High junction temperature up to 175 °C
- · Low forward voltage drop, negligible switching losses
- High efficiency

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- Switched mode power supply rectifier

4. Quick reference data

able 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				200		V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 146 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		15		A	
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 145 °C; both diodes conducting		30		A	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	$I_F = 15 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.88	0.95	V
I _R	reverse current	V _R = 200 V; T _i = 25 °C; per diode; <u>Fig. 7</u>		-	0.04	5	μA

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		
2	К	cathode		
3	A2	anode 2	0	K sym125
mb	К	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	name		method	quantity	version	issue date		
WN3S30S200CBT	TO263	WN3S30S200CBTJ	Reel	800	TO263d	17-Mar-2023		

7. Marking

Table 4. Marking codes	
Type number	Marking codes
WN3S30S200CBT	WN3S30S 200CBT

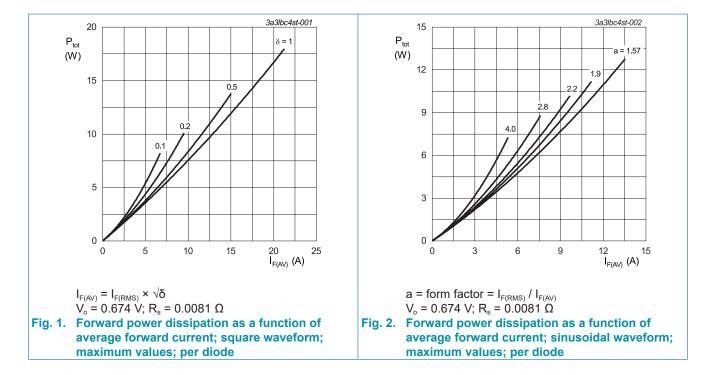
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

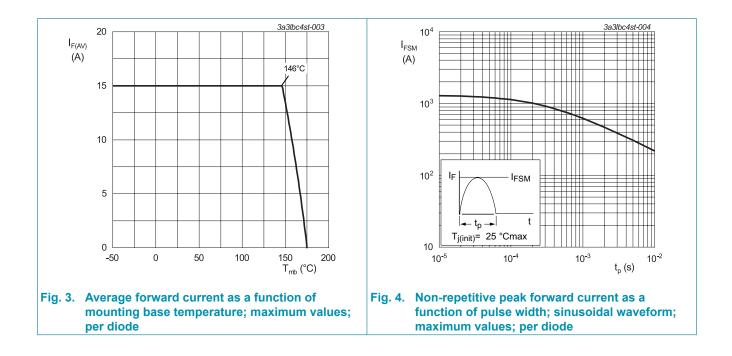
Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			200	V
V_{RWM}	crest working reverse voltage			200	V
V _R	reverse voltage	DC		200	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 146 °C; per diode; <u>Fig. 1; Fig. 2; Fig. 3</u>		15	A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 145 °C; both diodes conducting		30	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; per diode; <u>Fig. 4</u>		220	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		242	A
T _{stg}	storage temperature			-40 to 175	°C
Tj	junction temperature		[1]	-40 to 175	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$



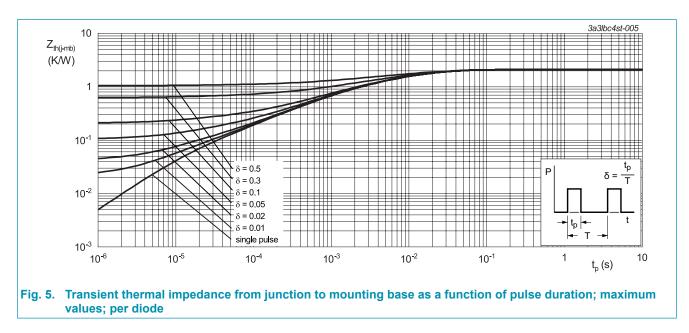
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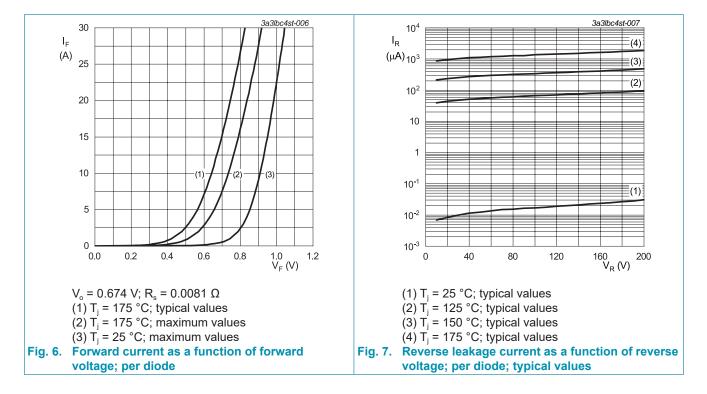
9. Thermal characteristics

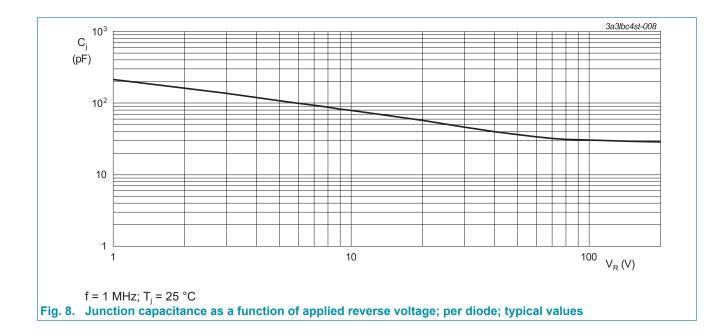
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	per diode; <u>Fig. 5</u>		-	-	2.1	K/W
		both diodes conducting		-	-	1.1	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W



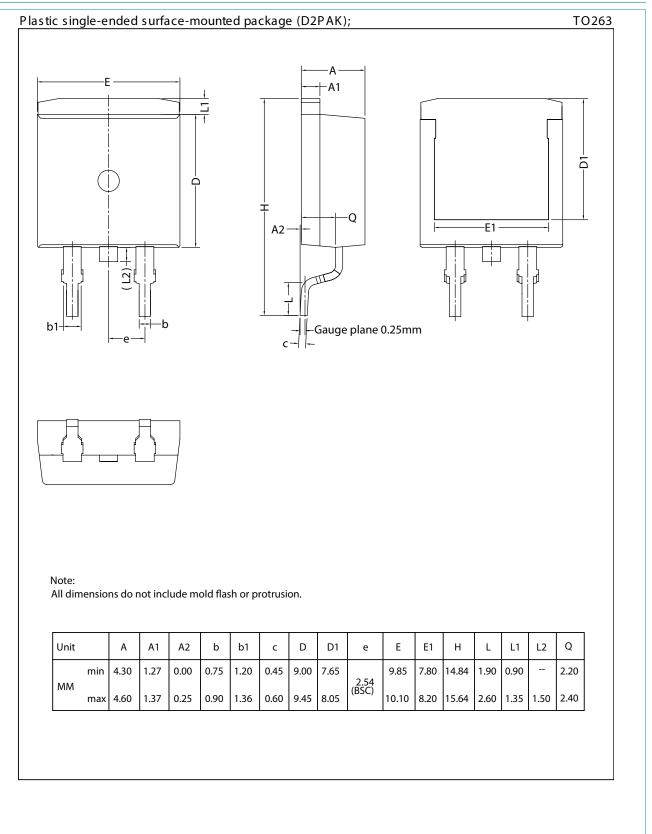
10. Characteristics

Table 7. Cł	naracteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Мах	Unit
Static cha	aracteristics						
V _F	forward voltage	$I_F = 15 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.88	0.95	V
		I_{F} = 15 A; T_{j} = 125 °C; per diode		-	0.77	-	V
		I _F = 15 A; T _j = 175 °C; per diode; <u>Fig. 6</u>		-	0.72	0.79	V
l _R	reverse current	V _R = 200 V; T _j = 25 °C; per diode; <u>Fig. 7</u>		-	0.04	5	μA
		V _R = 200 V; T _j = 125 °C; per diode; <u>Fig. 7</u>		-	0.1	-	mA





11. Package outline



WN3S30S200CBT

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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